NSN 5961-01-007-6853

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-007-6853 **Inclosure Material:** Metal and glass **Overall Length:** Between 0.190 inches and 0.210 inches **Overall Diameter:** Between 0.077 inches and 0.086 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.0 breakdown voltage, dc and 30.0 forward voltage, dc **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 82577-925959 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure:** Demilitarization: No